

## **isc Silicon NPN Power Transistor**

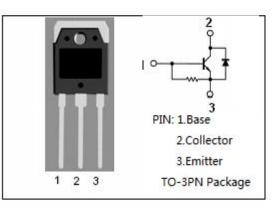
# 2SD1439

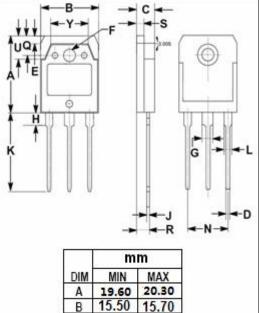
#### DESCRIPTION

- High Voltage
- High Switching Speed
- Built-in damper diode
- Wide Area of Safe Operation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **APPLICATIONS**

• Designed for use in horizontal deflection circuits of colour TV receivers.





|     | mm    |       |  |
|-----|-------|-------|--|
| DIM | MIN   | MAX   |  |
| Α   | 19.60 | 20.30 |  |
| В   | 15.50 | 15.70 |  |
| С   | 4.70  | 4.90  |  |
| D   | 0.90  | 1.10  |  |
| E   | 1.90  | 2.10  |  |
| F   | 3.40  | 3.60  |  |
| G   | 2.90  | 3.20  |  |
| Н   | 3.20  | 3.40  |  |
| J   | 0.595 | 0.605 |  |
| Κ   | 19.80 | 20.70 |  |
| L   | 1.90  | 2.20  |  |
| N   | 10.89 | 10.91 |  |
| Q   | 4.90  | 5.10  |  |
| R   | 3.35  | 3.45  |  |
| S   | 1.995 | 2.100 |  |
| U   | 5.90  | 6.20  |  |
| Y   | 9.90  | 10.10 |  |

## ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

| SYMBOL           | PARAMETER   | VALUE   | UNIT |  |
|------------------|---|---------|------|--|
| V <sub>CBO</sub> | Collector-Base Voltage                              | 1500    | V    |  |
| V <sub>CES</sub> | Collector-Emitter Voltage                           | 1500    | V    |  |
| V <sub>EBO</sub> | Emitter-Base Voltage                                | 5       | V    |  |
| Ι <sub>C</sub>   | Collector Current-Continuous                        | 3       | A    |  |
| I <sub>CP</sub>  | Collector Current-Peak                              | 10      | A    |  |
| I <sub>BP</sub>  | Base Current- Peak                                  | 3.5     | А    |  |
| Pc               | Collector Power Dissipation<br>@T <sub>c</sub> =25℃ | 50      |      |  |
|                  | Collector Power Dissipation<br>@Ta=25°C             | 2.5     | W    |  |
| Tj               | Junction Temperature                                | 130     | °C   |  |
| T <sub>stg</sub> | Storage Temperature Range                           | -55-130 | °C   |  |
|                  |   |         |      |  |



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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

| SYMBOL               | PARAMETER                            | CONDITIONS                                    | MIN | ТҮР | МАХ | UNIT |
|----------------------|--------------------------------------|---|-----|-----|-----|------|
| V <sub>(BR)EBO</sub> | Emitter-Base Breakdown Voltage       | I <sub>E</sub> = 200mA; I <sub>C</sub> = 0    | 5   |     |     | V    |
| V <sub>CE(sat)</sub> | Collector-Emitter Saturation Voltage | I <sub>C</sub> = 2Α; I <sub>B</sub> = 0.75Α   |     |     | 5.0 | V    |
| V <sub>BE(sat)</sub> | Base-Emitter Saturation Voltage      | I <sub>C</sub> = 2Α; I <sub>B</sub> = 0.75Α   |     |     | 1.5 | V    |
| h <sub>FE</sub>      | DC Current Gain                      | I <sub>C</sub> = 2A ; V <sub>CE</sub> = 10V   | 4   |     | 12  |      |
| Ісво                 | Collector Cutoff Current             | V <sub>CB</sub> = 750V; I <sub>E</sub> = 0    |     |     | 50  | μA   |
|                      |                                      | V <sub>CB</sub> = 1500V; I <sub>E</sub> = 0   |     |     | 1.0 | mA   |
| V <sub>ECF</sub>     | C-E Diode Forward Voltage            | I <sub>F</sub> = 2A                           |     |     | 2.2 | V    |
| f⊤                   | Transition Frequency                 | I <sub>C</sub> = 0.5A ; V <sub>CE</sub> = 10V |     | 2   |     | MHz  |

Switching Times

| ts | Storage Time | I <sub>C</sub> = 2A; I <sub>B</sub> = 0.75A; L <sub>leak</sub> = 5 μ Η |  | 7    | μs         |
|----|--------------|--|--|------|------------|
| tf | Fall Time    |  |  | 0.75 | μ <b>S</b> |

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